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TSMC-03-627

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April 30, 2004

To: Commissioner for Patents

P.O.Box 1450

Alexandria, VA 22313-1450

Fr: George O. Saile, Reg. No. 19,572

28 Davis Avenue

Poughkeepsie, N.Y. 12603

Subject:

Serial No. 10/807,081 03/23/04

Hung-Wei Chen et al.

METHOD FOR REDUCING A SHORT CHANNEL EFFECT FOR NMOS DEVICES IN SOI

CIRCUITS

INFORMATION DISCLOSURE STATEMENT

Enclosed is Form PTO-1449, Information Disclosure Citation
In An Application.

The following Patents and/or Publications are submitted to comply with the duty of disclosure under CFR 1.97-1.99 and 37 CFR 1.56.

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on May 4, 2004.

Stephen B. Ackerman, Reg.# 37761

Signature/Date

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- U.S. Patent 5,468,657 to Hsu, "Nitridation of SIMOS Buried Oxide," discloses a method for improving the electrical isolation between surface regions and underlying support regions in SIMOX buried oxide wafers.
- U.S. Patent 6,613,678 to Sakaguchi et al., "Process for Manufacturing a Semiconductor Substrate as Well as a Semiconductor Thin Film, and Multilayer Structure," discloses a process for manufacturing a semiconductor substrate as well as a semiconductor thin film.
- U.S. Patent 6,410,938 to Xiang, "Semiconductor-on-Insulator Device with Nitrided Buried Oxide and Method of Fabricating," discloses methods of preventing dopant depletion in active regions of semiconductor devices.
- U.S. Patent 5,910,672 to Iwamatsu et al., "Semiconductor Device and Method of Manufacturing the Same," discloses a semiconductor device with a SOI structure and a method of manufacturing the same, preventing deterioration in and making improvement in device characteristics.

U.S. Patent 5,656,537 to Iwamatsu et al., "Method of Manufacturing a Semiconductor Device Having SOI Structure," discusses a method of manufacturing a semiconductor device having an SOI (Semiconductor On Insulator) structure.

Sincerely,

Stephen B. Ackerman,

Reg. No. 37761

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